NSN 5961-01-321-9947

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View Online at https://aerobasegroup.com/nsn/5961-01-321-9947 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 400.00 gate to substrate voltage and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 81349-mil-s-19500/384 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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